

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	3176	(257/328-334).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/26 14:59
S2	2758	S1 and (@ad<="20030724" or @rlad<="20030724")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/26 14:59
S3	801	(hoshino-takashi harada-shin fujikwa-kazuhiro hatsukawa-satoshi hirotzu-kenichi).in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/26 14:56
S4	56	S3 and transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/11 15:27
S5	2	("20010024138").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/11 12:19
S6	4	"522278".ap.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/11 15:27
S7	99	"vertical junction field effect transistor"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/26 14:56
S8	76	S7 and (@ad<="20030724" or @rlad<="20030724")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/26 14:56

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S9	709	(257/302).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/09/26 14:59
S10	644	S9 and (@ad<="20030724" or @rlad<="20030724")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/09/26 14:59

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	32	(drift and buried and gate and channel and semiconductor).clm.	US-PGPUB	OR	ON	2006/09/26 16:52